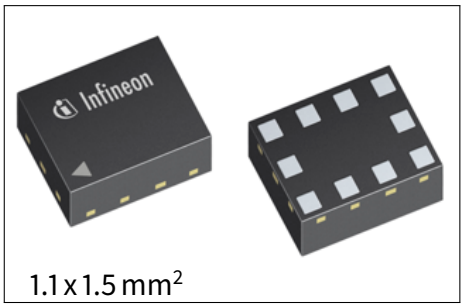
BGSA12GN10

Single Pole Dual Throw Antenna Tuning Switch

Features

- Designed for high linearity and high RF voltage tuning applications
- Multiple selectable switch configurations:
  Each throw directly and independently controlled
- Low R_{ON} resistance of 1.6 Ω at each port in ON state
- Low C_{OFF} capacitance of 120 fF at each port in OFF state
- High bidirectional RF operating voltage of 36 V in OFF state
- Low harmonic generation
- GPIO control interface
- Supply voltage range: 1.65 to 3.6 V
- No RF parameter change within supply voltage range
- Small form factor 1.1 mm x 1.5 mm (MSL1, 260°C per JEDEC J-STD-020)
- RoHS and WEEE compliant package



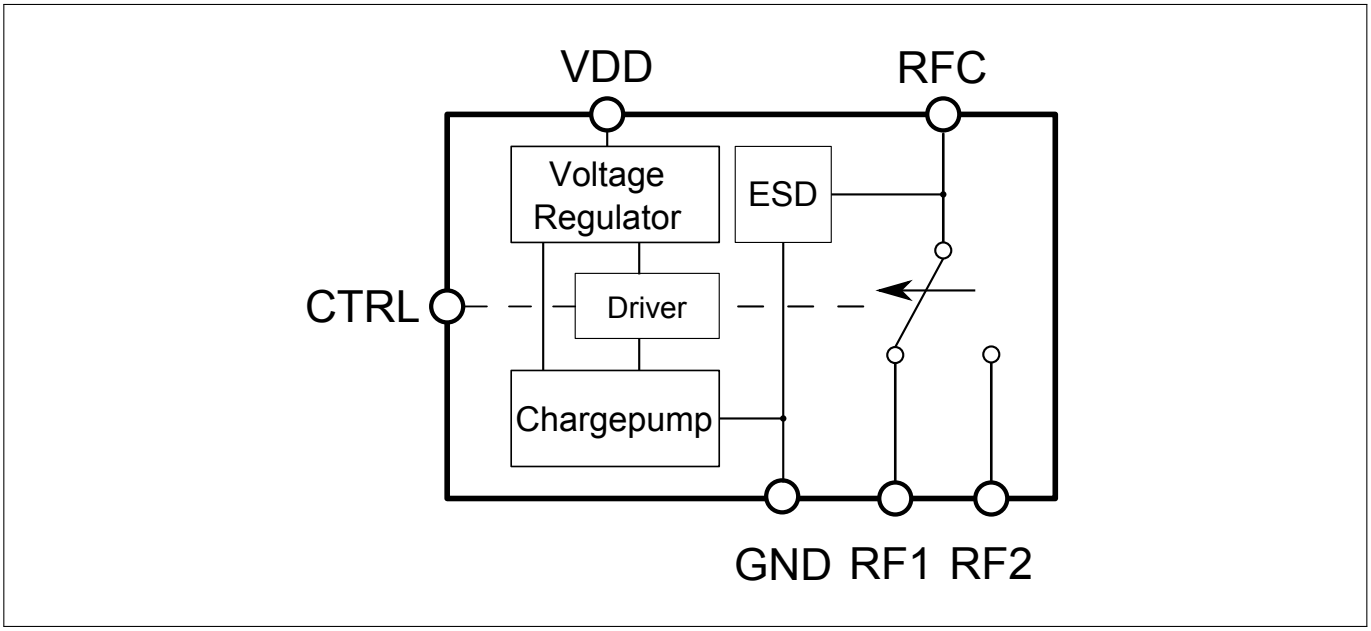
Potential Applications

- Impedance Tuning
- Antenna Tuning
- Inductance Tuning
- Tunable Filters

Product Validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Block Diagram



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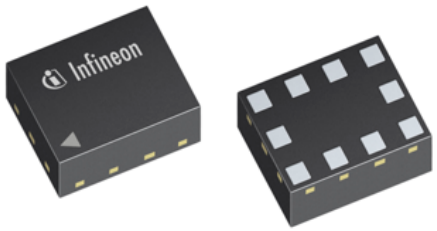
1 Features



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RoHS Halogen-Free Lead-Free Green

Description

The BGSA12GN10 is a Single Pole Dual Throw (SPDT) RF antenna aperture switch optimized for low C_{OFF} enabling applications up to 6.0 GHz. This single supply chip integrates on-chip CMOS logic driven by a simple, single-pin CMOS or TTL compatible control input signal. Unlike GaAs technology, the 0.1dB compression point exceeds the switch maximum input power level, resulting in linear performance at all signal levels and external DC blocking capacitors at the RF ports are only required if DC voltage is applied externally. Due to its very high RF voltage ruggedness it is suited for switching any reactive devices such as inductors and capacitors in RF matching circuits without significant losses in quality factors.

Product Name	Marking	Package
BGSA12GN10	A2	TSNP-10-1/TSNP-10-2

2 Maximum Ratings

Table 1: Maximum Ratings, Table I at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Frequency Range	f	0.1	–	–	GHz	[1]
Supply voltage [2]	V_{DD}	-0.5	–	3.6	V	Only for infrequent and short duration time periods
Storage temperature range	T_{STG}	-55	–	150	°C	–
RF input power	P_{RF_max}	–	–	39	dBm	Pulsed RF input power, duty cycle of 25 % with T_period= 4620 µs, ON-state, setup as of Fig. 1
RF voltage	V_{RF_max}	–	–	48	V	Short term peaks (1µs, duty cycle 0.1%), Isolation mode, test setup acc. Fig. 2 / Fig. 3 and exceeding typical linearity, R_{ON} and C_{OFF} parameters
ESD capability, CDM [3]	$V_{ESD_{CDM}}$	-1.5	–	+1.5	kV	
ESD capability, HBM [4]	$V_{ESD_{HBM}}$	-1	–	+1	kV	
ESD capability, system level (RF port) [5]	$V_{ESD_{ANT}}$	-8	–	+8	kV	RF vs system GND, with 27 nH shunt inductor
Junction temperature	T_J	–	–	125	°C	–
Thermal resistance junction - soldering point	R_{thJS}	–	–	45	K/W	–
Maximum DC-voltage on RF-Ports and RF-Ground	V_{RFDC}	0	–	0	V	No DC voltages allowed on RF-Ports
Control Voltage Levels	V_{Ctrlx}	-0.7	–	V_{DD}+0.7 (max. 3.6)	V	–
Moisture Sensitivity Level	MSL	–	1	–		–

[1] Switch has a low-pass response. For higher frequencies, losses have to be considered for their impact on thermal heating. The DC voltage at RF ports V_{RFDC} has to be 0 V.
[2] Note: Consider potential ripple voltages on top of V_{IO}. Including RF ripple, V_{IO} must not exceed the maximum ratings: $V_{Ctrl} = V_{DC} + V_{Ripple}$.
[3] Field-Induced Charged-Device Model ANSI/ESDA/JEDEC JS-002. Simulates charging/discharging events that occur in production equipment and processes. Potential for CDM ESD events occurs whenever there is metal-to-metal contact in manufacturing.
[4] Human Body Model ANSI/ESDA/JEDEC JS-001 (R = 1,5 kΩ, C = 100 pF).
[5] IEC 61000-4-2 (R = 330 Ω, C = 150 pF), contact discharge.

Warning: Stresses above the max. values listed here may cause permanent damage to the device. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit. Exposure to conditions at or below absolute maximum rating but above the specified maximum operation conditions may affect device reliability and life time. Functionality of the device might not be given under these conditions.

Maximum Ratings

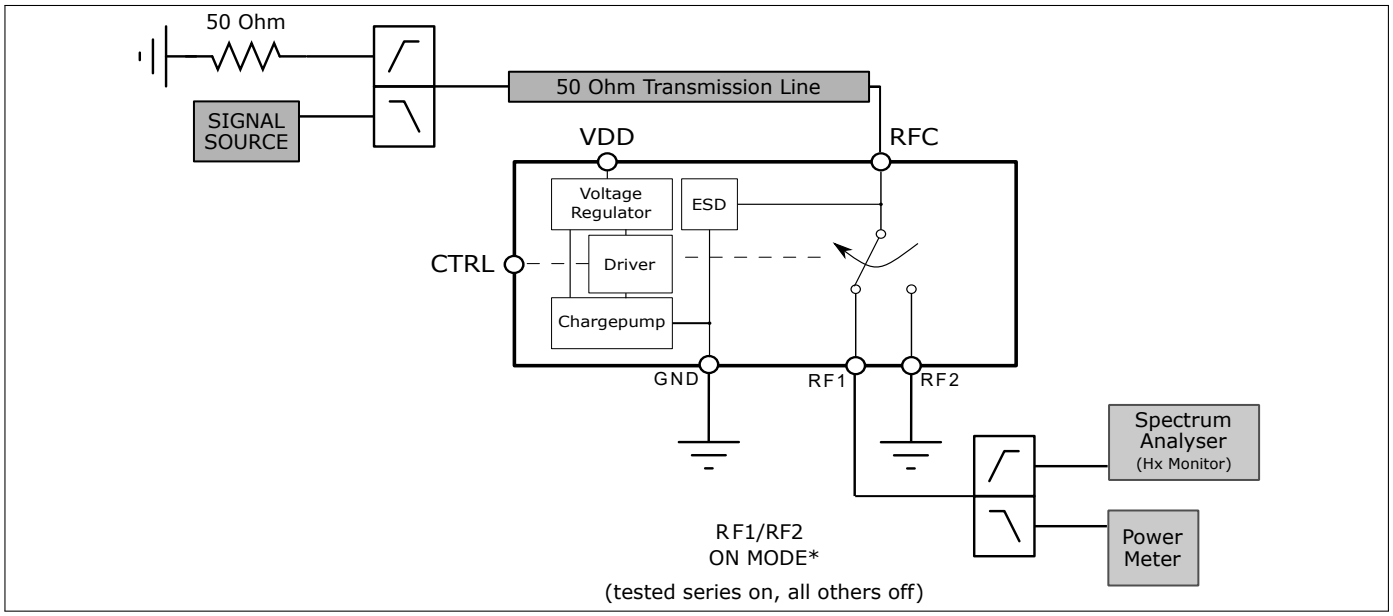

Figure 1: RF operating and Harmonics generation measurement configuration - RFx ON mode

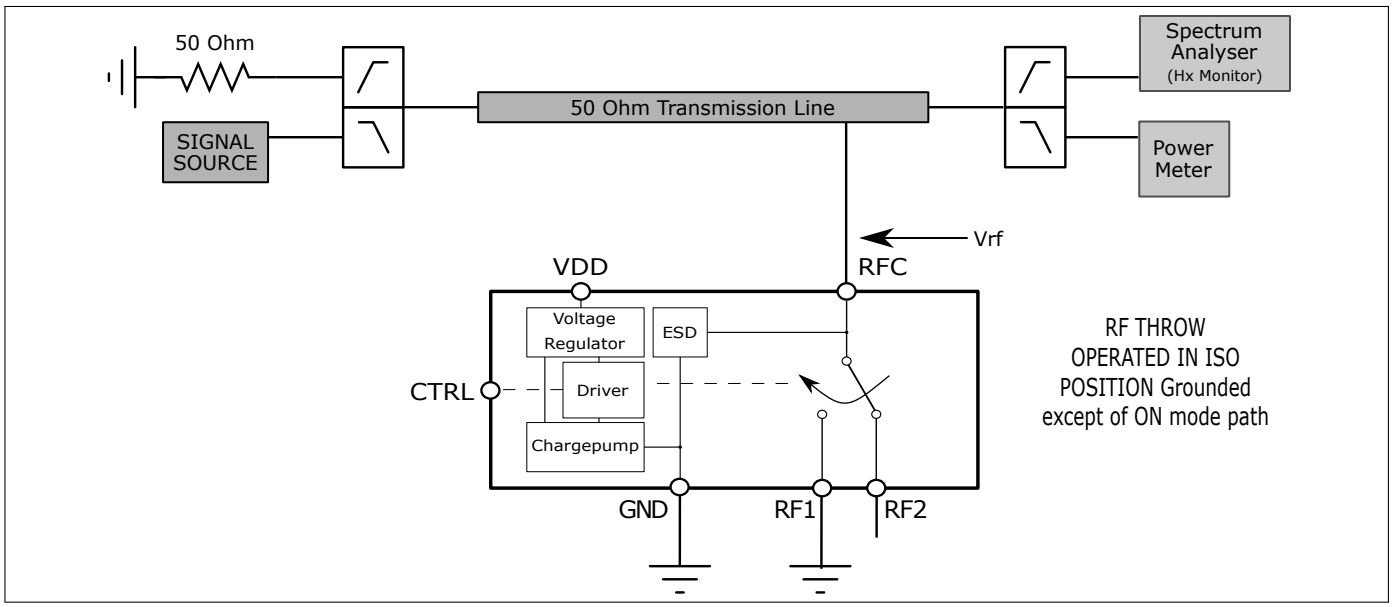

Figure 2: RF operating voltage measurement configuration - OFF mode at RFC

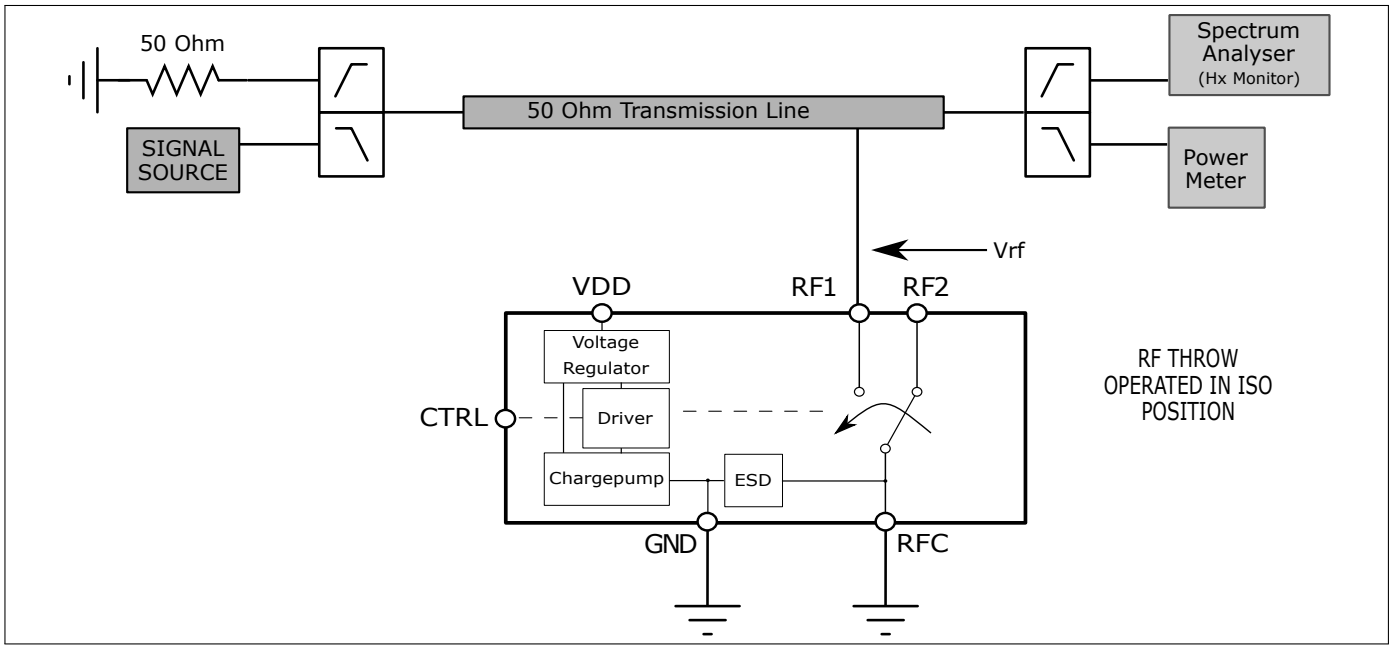

Figure 3: RF operating voltage measurement configuration - OFF mode at RFx

3 DC Characteristics

Table 2: DC Characteristics at T_A = −40 °C to 85 °C

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply voltage	V_{DD}	1.65	2.8	3.6	V	–
Supply current	I_{DD}	–	80	150	µA	–
Control voltage low	$V_{Ctrl,low}$	0	–	0.45	V	–
Control voltage high	$V_{Ctrl,high}$	1.2	1.8	2.85	V	$V_{Ctrl,high} < V_{DD}$
Control current low	$I_{Ctrl,low}$	-1	0	1	µA	–
Control current high	$I_{Ctrl,high}$	-1	0	1	µA	$V_{Ctrl,high} < V_{DD}$
Ambient temperature	T_A	-40	25	85	°C	–
RF switching time	t_{ST}	2	5	7	µs	P_{IN} = 0 dBm, $Z_0 = 50\,\Omega$, $T_A = -40\,°C ... + 85\,°C$ V_{DD} = 1.65 – 3.6 V
Startup time	t_{Pup}	–	20	30	µs	Refering Fig. 4 and Fig. 5

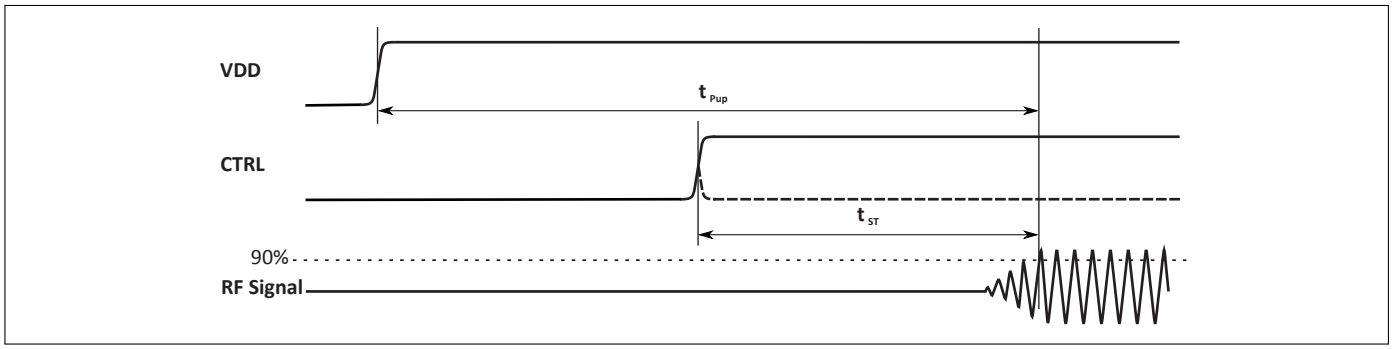

Figure 4: Switching Time Definition

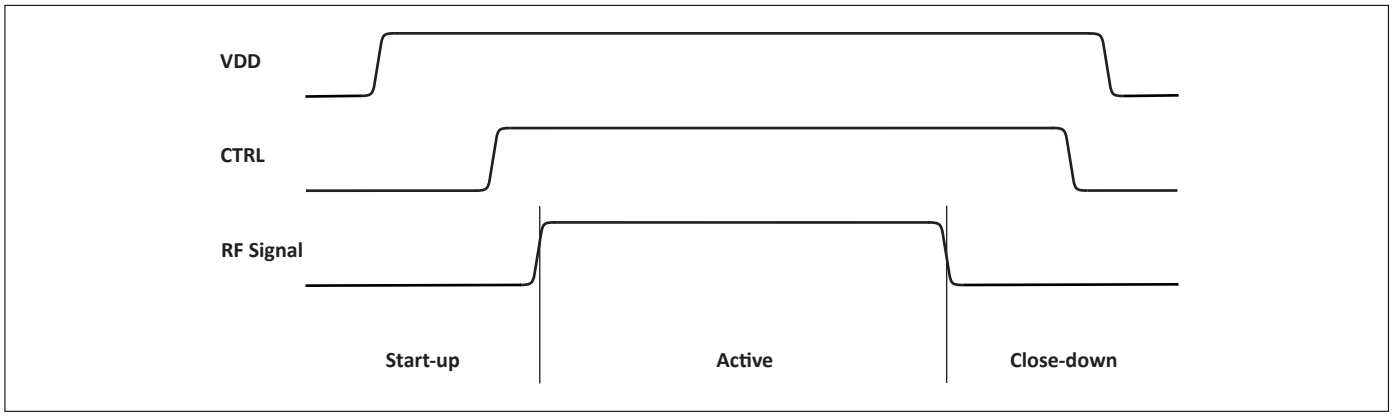

Figure 5: Timing of Control and RF signals for valid operation

4 RF small signal parameter

Table 3: RF small signal specifications

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Frequency range	f	0.1	–	6.0	GHz	–
Switch ON resistance	R_{ON}	–	1.6		Ω	RFx to RFC
Switch OFF capacitance	C_{OFF}	–	120		fF	RFx to RFC
Parasitic RF shunt capacitance	$C_{SH,PAR}$	–	42		fF	RFx to GND, extracted value for 2 GHz
Switch series inductance	L_{SER}	–	0.1		nH	
Insertion Loss [1,2,3,4,5]						
824 - 960 MHz	*IL*	–	0.25	0.35	dB	–
1710 - 1980 MHz		–	0.32	0.42	dB	–
1980 - 2170 MHz		–	0.33	0.42	dB	–
2170 - 2690 MHz		–	0.39	0.49	dB	–
Return Loss[1,2,3,4,5]						
All Ports @ 824 - 915 MHz	*RL*	27.9	32	38	dB	–
All Ports @ 1710 - 2170 MHz		22	25	30	dB	–
All Ports @ 2170 - 2690 MHz		20	23	27	dB	–
Isolation RFx to RFC[1,2,3,4,5]						
824 - 915 MHz	*ISO*	28.5	30	30	dB	–
1710 - 1980 MHz		22	23	24	dB	–
1980 - 2170 MHz		22	22	23	dB	–
2170 - 2690 MHz		19	20	21	dB	–
Isolation RFx to RFx[1,2,3,4,5]						
824 - 915 MHz	*ISO*	29.5	30	31	dB	–
1710 - 1980 MHz		22	23	24	dB	–
1980 - 2170 MHz		21	22	23	dB	–
2170 - 2690 MHz		19	20	21	dB	–

[1] Terminating Port Impedance: $Z_0 = 50\,\Omega$ [2] Input Power: $P_{IN} = -20\,dBm$ [3] Temperature Range: $T_A = -40\,°C$... $+85\,°C$, [4] Supply Voltage: $V_{DD} = 1.65 - 3.6\,V$ [5] On application board without any matching components

5 RF large signal parameter

Table 4: RF large signal specifications

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
RF operating voltage	V_{RF_peak}	–	–	36	V	
Harmonic Generation up to 12.75 GHz[1,2,3]						
All RF Ports - Second Order Harmonics	P_{H2}	–	105	–	dBc	25 dBm, 50Ω, f_0 = 786 MHz
All RF Ports - Third Order Harmonics	P_{H3}	–	115	–	dBc	25 dBm, 50Ω, f_0 = 786 MHz
All RF Ports - Second Order Harmonics	P_{H2}	–	93	–	dBc	36 dBm, 50Ω, f_0 = 824 MHz
All RF Ports - Third Order Harmonics	P_{H3}	–	94	–	dBc	33 dBm, 50Ω, f_0 = 824 MHz
All RF Ports	P_{Hx}	105	–	–	dBc	25 dBm, 50Ω, CW mode
Intermodulation Distortion IMD2 [1,2,3]						
IIP2, low	IIP2,l	–	110	–	dBm	IIP2 conditions table 8
IIP2, high	IIP2,h	–	120	–	dBm	
Intermodulation Distortion IMD3 [1,2,3]						
IIP3	IIP3	–	75	–	dBm	IIP3 conditions table 9
SV LTE Intermodulation [1,2,3]						
IIP3,SVLTE	IIP3,SV	–	75	–	dBm	SV-LTE conditions table 10

[1] Terminating Port Impedance: $Z_0 = 50\ \Omega$ [2] Supply Voltage: V_{DD} = 1.65 – 3.6 V [3] On application board without any matching components

Table 5: IIP2 conditions table

Band	In-Band Frequency [MHz]	Blocker Frequency 1 [MHz]	Blocker Power 1 [dBm]	Blocker Frequency 2 [MHz]	Blocker Power 2 [dBm]
Band 1 Low	2140	1950	20	190	-15
Band 1 High	2140	1950	20	4090	-15
Band 5 Low	881.5	836.5	20	45	-15
Band 5 High	881.5	836.5	20	1718	-15

Table 6: IIP3 conditions table

Band	In-Band Frequency [MHz]	Blocker Frequency 1 [MHz]	Blocker Power 1 [dBm]	Blocker Frequency 2 [MHz]	Blocker Power 2 [dBm]
Band 1	2140	1950	20	1760	-15
Band 5	881.5	836.5	20	791.5	-15

Table 7: SV-LTE conditions table

Band	In-Band Frequency [MHz]	Blocker Frequency 1 [MHz]	Blocker Power 1 [dBm]	Blocker Frequency 2 [MHz]	Blocker Power 2 [dBm]
Band 5	872	827	23	872	14
Band 13	747	786	23	747	14
Band 20	878	833	23	2544	14

6 Logic Truth Table

Table 8: Modes of Operation

State	Mode	CTRL
1	RF1 to RFc	0
2	RF2 to RFc	1

Mapping of Switch Rows to Bit: ON = 1, OFF = 0

7 Application Information

Pin Configuration and Function

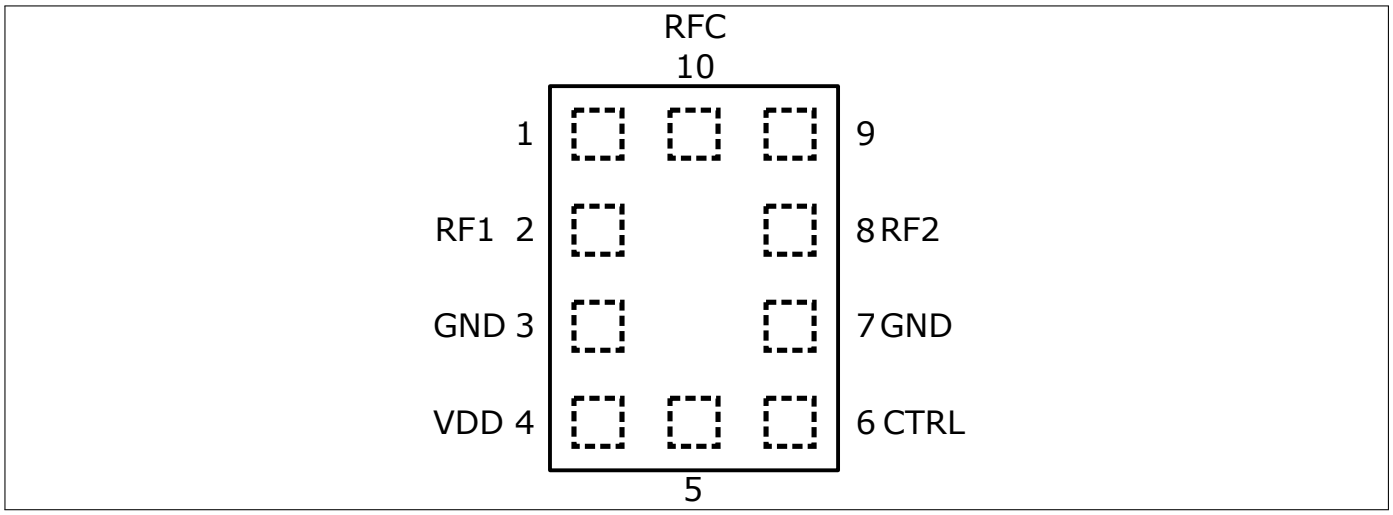

Figure 6: BGSA12GN10 Pin Configuration (top view)

Table 9: Pin Definition and Function

Pin No.	Name	Function
1	N.C.	Not connected
2	RF1	RF1 port
3	GND	Ground
4	VDD	Power Supply
5	N.C.	Not connected
6	CTRL	GPIO digital control line
7	GND	Ground
8	RF2	RF2 port
9	N.C.	Not connected
10	RFC	Common RF

8 Package Information

Table 10: Mechanical Data

Parameter	Symbol	Value	Unit
X-Dimension	*X*	1.1 ± 0.05	*mm*
Y-Dimension	*Y*	1.5 ± 0.05	*mm*
Size	*Size*	2.25	mm^2
Height	*H*	0.375 +0.025/−0.015	*mm*

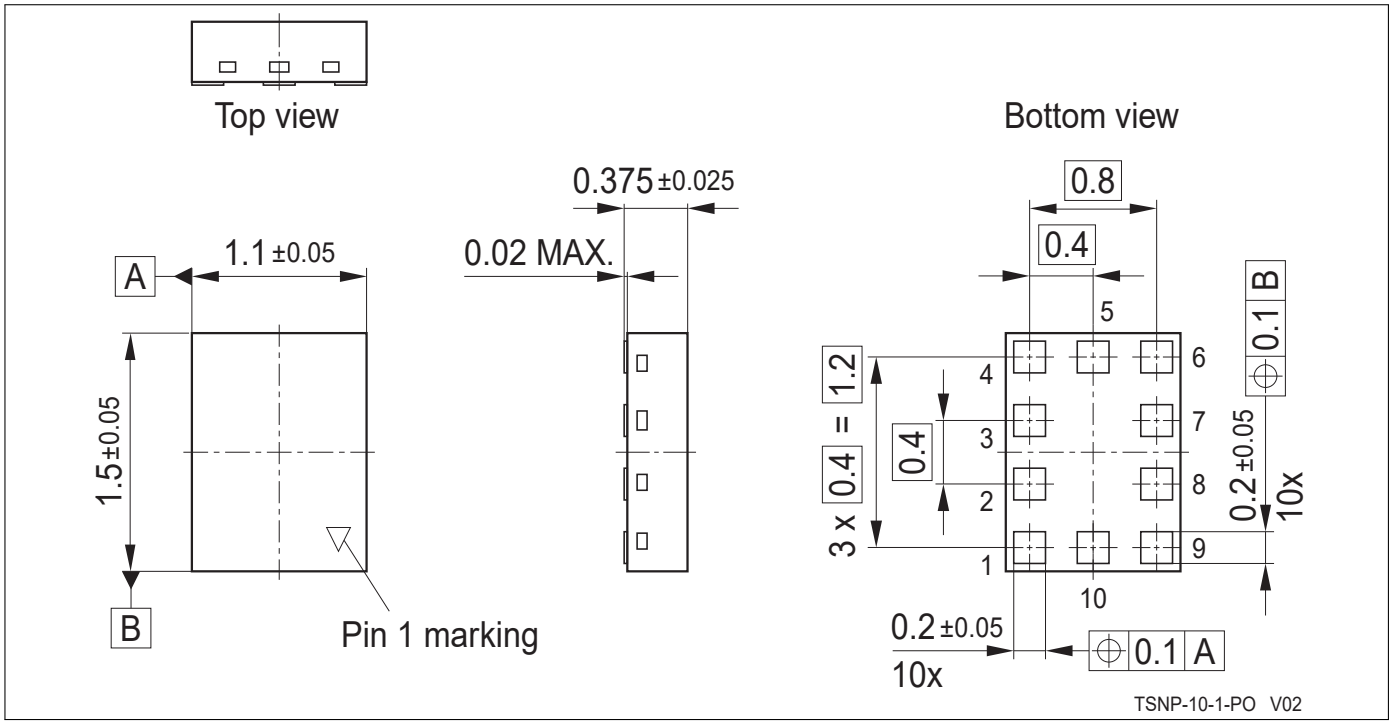

Figure 7: TSNP-10-1 Package Outline (top, side and bottom views)

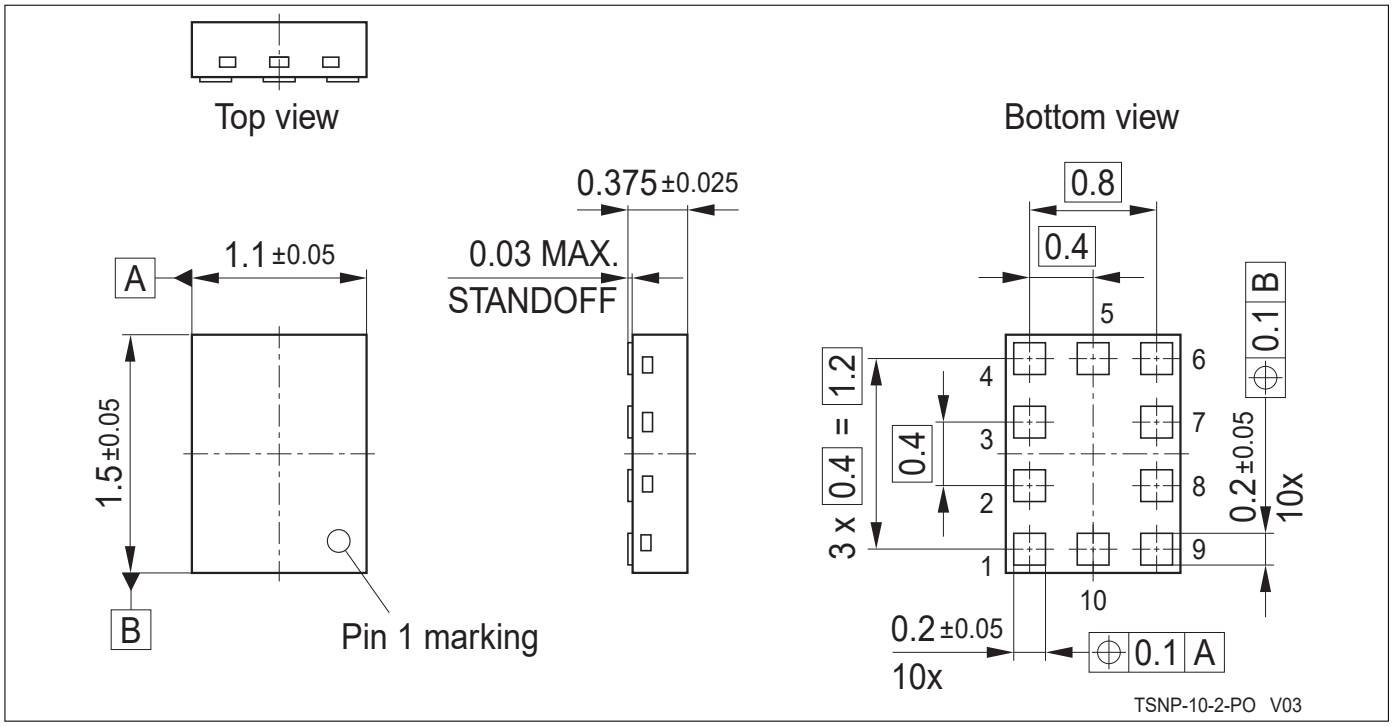

Figure 8: TSNP-10-2 Package Outline (top, side and bottom views)

Table 11: Year date code marking - digit "Y"

Year	"Y"	Year	"Y"	Year	"Y"
2010	0	2020	0	2030	0
2011	1	2021	1	2031	1
2012	2	2022	2	2032	2
2013	3	2023	3	2033	3
2014	4	2024	4	2034	4
2015	5	2025	5	2035	5
2016	6	2026	6	2036	6
2017	7	2027	7	2037	7
2018	8	2028	8	2038	8
2019	9	2029	9	2039	9

Table 12: Week date code marking - digit "W"

Week	"W"	Week	"W"	Week	"W"	Week	"W"	Week	"W"
1	A	12	N	23	4	34	h	45	v
2	B	13	P	24	5	35	j	46	x
3	C	14	Q	25	6	36	k	47	y
4	D	15	R	26	7	37	l	48	z
5	E	16	S	27	a	38	n	49	8
6	F	17	T	28	b	39	p	50	9
7	G	18	U	29	c	40	q	51	2
8	H	19	V	30	d	41	r	52	3
9	J	20	W	31	e	42	s	53	M
10	K	21	Y	32	f	43	t		
11	L	22	Z	33	g	44	u		

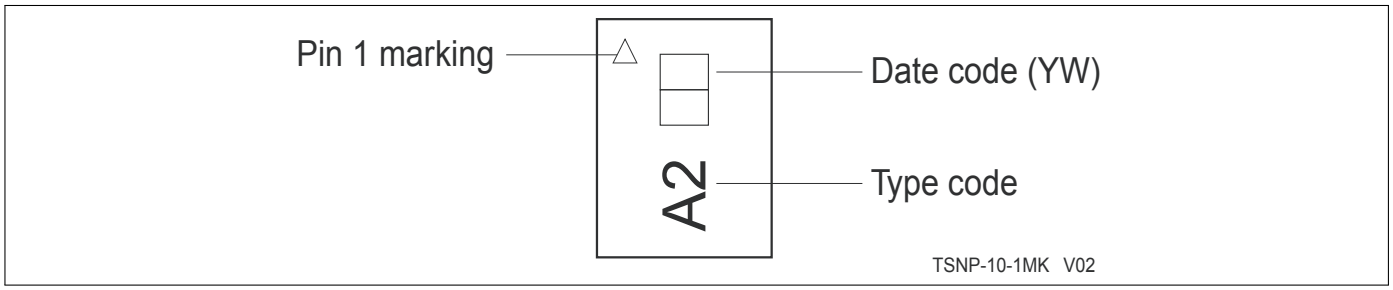

Figure 9: TSNP10-1 Marking Specification (top view): Date code digits Y and W defined in Table 11/12

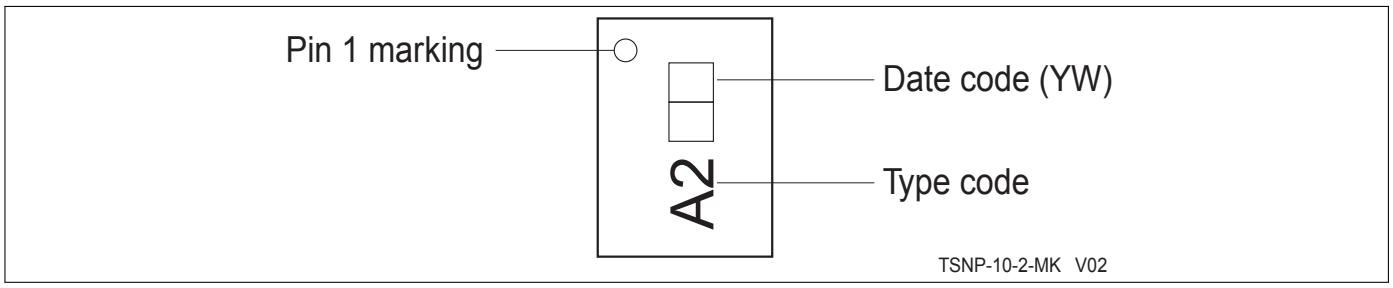

Figure 10: TSNP10-2 Marking Specification (top view): Date code digits Y and W defined in Table 11/12

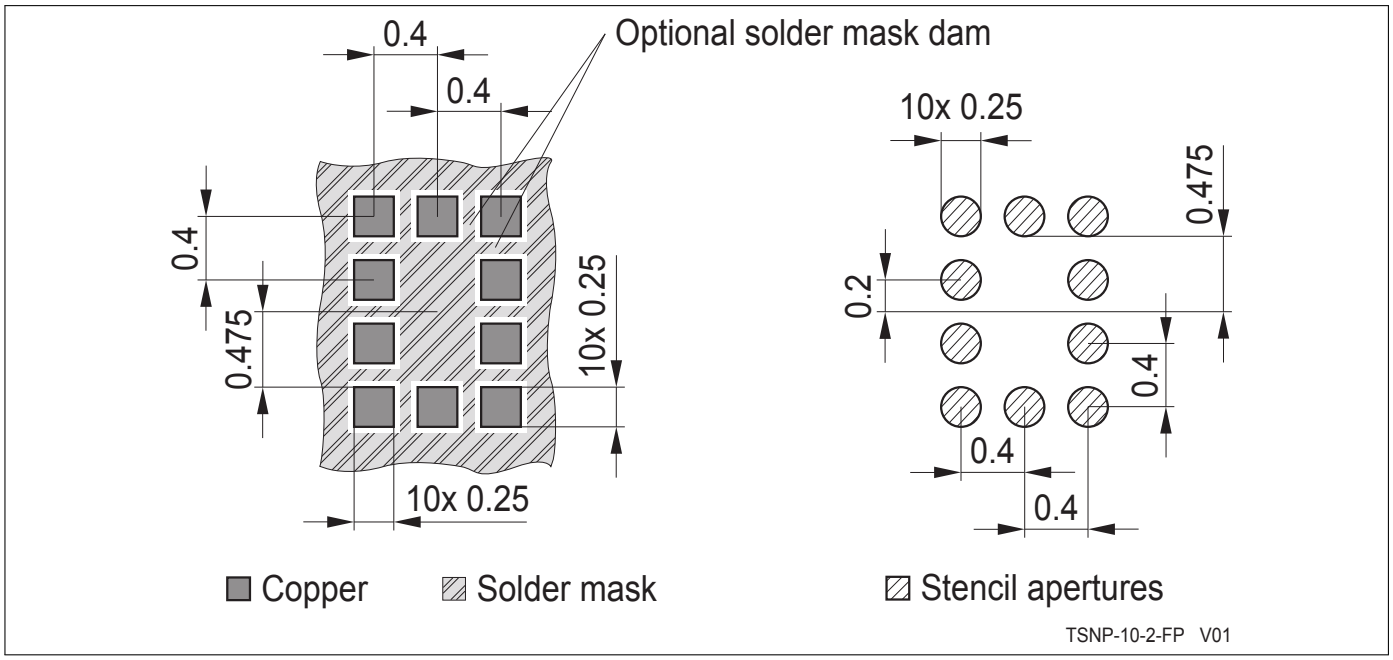

Figure 11: Land pattern and stencil mask (TSNP-10-1/-2)

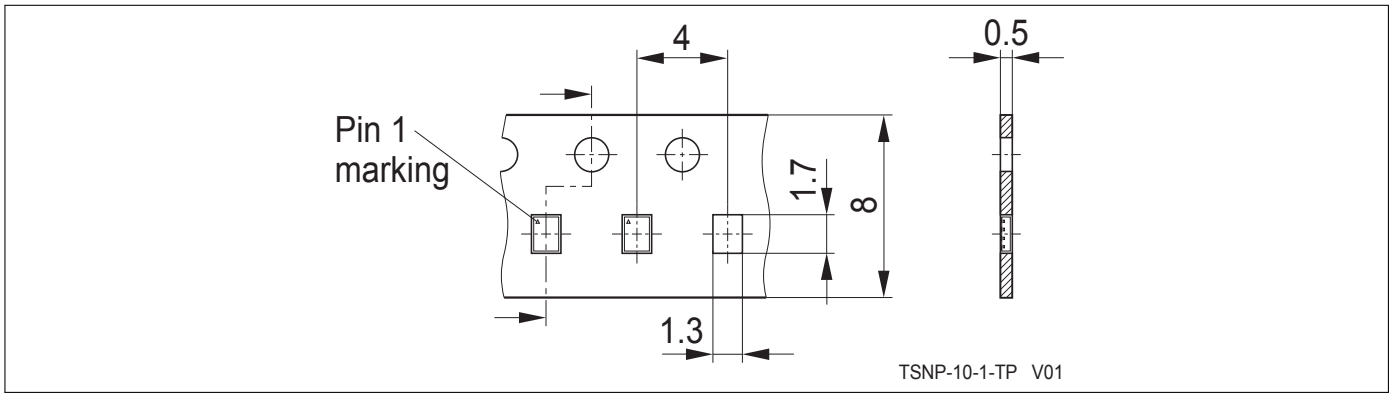

Figure 12: Carrier Tape (TSNP-10-1)

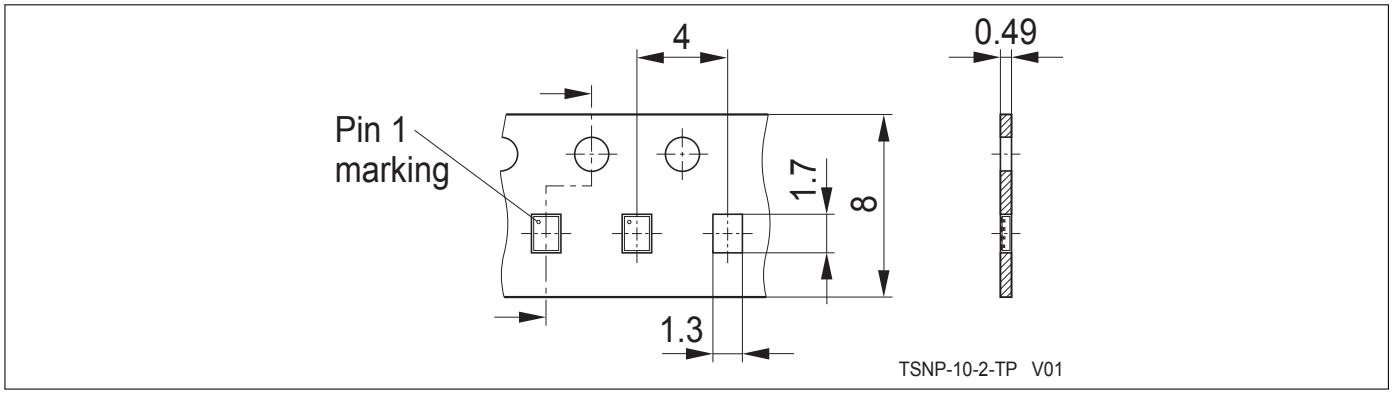

Figure 13: Carrier Tape (TSNP-10-2)

Revision History	
Creation of document Revision 3.1, 2020-07-02	
Page or Item	**Subjects (major changes since previous revision)**
5	Typo at max. control current high corrected
10	Typo in pin configuration and function corrected

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